

AllnGaP LED DICE

Part NO.: AOC-112RxC Series

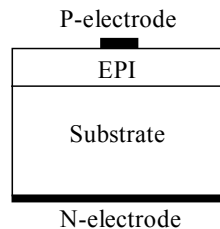
Features

- Red Color Emission
- Excellent performance and high efficiency
- Great reliability even in harsh environment

Description

AOC-112RxC series is a red color emitting AllnGaP LED grown by MOCVD technique. Its structure enables enhanced quantum efficiency and therefore a greater light intensity. This device is designed to suit the growing demand in the compact size electronic goods.

Chip Dimensions



Chip Size : 10.8mil×10.8mil±0.5mil
Bonding Pad : φ3.8mil±0.3mil
Chip Thickness : 6.5mil±1.0mil

Specification and Optical Characteristics

Measuring Item	Symbol	Condition	Min	Typ	Max	Unit
Forward Voltage	V_F	$I_F=20mA$	1.70	-	2.20	V
Reverse Current	I_R	$V_R=-5V$	-	-	1.0	μA
Dominant Wavelength	λ_d	$I_F=20mA$	616	-	645	nm
Max. Junction Temperature	T_{max}	-	≤ 115			$^{\circ}C$
Max. DC forward current	I_f	$T_a = 25^{\circ}C$	≤ 50			mA
Max. pulse forward current (Pulse width 0.1 msec, frequency=1 kHz.)	I_{fm}	$T_a = 25^{\circ}C$	≤ 100			mA
Storage temperature	T_{stg}	Chip on tape	0 ~ 40			$^{\circ}C$
		Only chip	-40 ~ 80			

Available Dominate Wavelength and Iv Matrix

Part No.	Wavelength Range	≥ 50	≥ 60	≥ 70	≥ 80	≥ 90	≥ 100	≥ 110	≥ 120	≥ 130	≥ 140	≥ 150	≥ 160
		mcd	mcd	mcd	mcd	mcd	mcd	mcd	mcd	mcd	mcd	mcd	mcd
112RSC	616~625 nm	-	-	-	-	-	-	-	-	L	M	N	-
112RMC	620~630 nm	-	-	-	-	-	I	J	K	L	-	-	-
112RRC	635~645 nm	D	E	-	-	-	-	-	-	-	-	-	-

Not:

1. All measurements are done with AOC's standard testing equipment.
2. Luminance intensity is measured on bare chip.
3. Above contents are subject to change without notice.
4. Special requests are also welcome, please contact AOC's sale representative for any request.